# NSN 5961-00-470-8290

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Inclosure Material:

Metal

**Overall Length:** 

0.340 inches

#### **Overall Diameter:**

0.620 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage, dc and 60.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

## Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

# Fiig:

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